

**GLASS PASSIVATED JUNCTION  
SILICON RECTIFIER**

**VOLTAGE RANGE 50 to 1000 Volts CURRENT 1.0 Ampere**

**FEATURES**

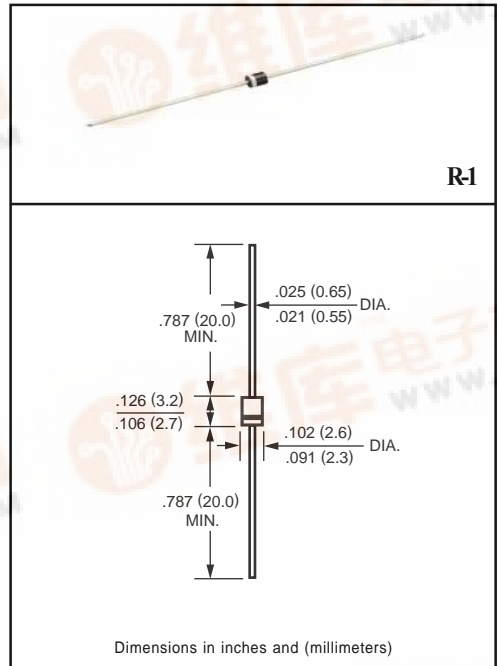
- \* High reliability
- \* Low leakage
- \* Low forward voltage drop
- \* High current capability
- \* Glass passivated junction

**MECHANICAL DATA**

- \* Case: Molded plastic black body
- \* Epoxy: Device has UL flammability classification 94V-0
- \* Lead: MIL-STD-202E method 208C guaranteed
- \* Mounting position: Any
- \* Weight: 0.19 gram

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Ratings at 25 °C ambient temperature unless otherwise specified.  
Single phase, half wave, 60 Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.



**MAXIMUM RATINGS** (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	1A1G	1A2G	1A3G	1A4G	1A5G	1A6G	1A7G	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at TA = 25°C	IO	1.0							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	IFSM	25							Amps
Typical Junction Capacitance (Note)	CJ	15							pF
Typical Thermal Resistance	R θJA	60							°C/W
Operating and Storage Temperature Range	TJ, TSTG	-65 to + 175							°C

**ELECTRICAL CHARACTERISTICS** (At TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	1A1G	1A2G	1A3G	1A4G	1A5G	1A6G	1A7G	UNITS
Maximum Instantaneous Forward Voltage at 1.0A DC	VF	1.1							Volts
Maximum DC Reverse Current @ TA = 25°C	IR	5.0							uAmps
at Rated DC Blocking Voltage @ TA = 100°C		50							
Maximum Full Load Reverse Current Full Cycle Average @ 375° (9.5mm) lead length at TL = 75°C		30							

NOTES: 1. Measured at 1 MHz and applied reverse voltage of 4.0 volts

## RATING AND CHARACTERISTIC CURVES ( 1A1G THRU 1A7G )

